



# Precision, High Speed, JFET Input Operational Amplifiers

## FEATURES

- *Guaranteed* Offset Voltage  
-55°C to 125°C  
150μV Max  
500μV Max  
4μV/°C Max
- *Guaranteed* Drift  
70°C  
125°C  
150pA Max  
2.5nA Max  
12V/μs Min
- *Guaranteed* Bias Current  
70°C  
125°C  
150pA Max  
2.5nA Max  
12V/μs Min
- *Guaranteed* Slew Rate  
12V/μs Min

## APPLICATIONS

- Precision, High Speed Instrumentation
- Logarithmic Amplifiers
- D/A Output Amplifiers
- Photodiode Amplifiers
- Voltage-to-Frequency Converters
- Frequency-to-Voltage Converters
- Fast, Precision Sample-and-Hold

## DESCRIPTION

The LT1055/LT1056 JFET input operational amplifiers combine precision specifications with high speed performance.

For the first time, 16V/μs slew rate and 6.5MHz gain-bandwidth product are simultaneously achieved with offset voltage of typically 50μV, 1.2μV/°C drift, bias currents of 40pA at 70°C and 500pA at 125°C.

The 150μV maximum offset voltage specification is the best available on any JFET input operational amplifier.

The LT1055 and LT1056 are differentiated by their operating currents. The lower power dissipation LT1055 achieves lower bias and offset currents and offset voltage. The additional power dissipation of the LT1056 permits higher slew rate, bandwidth and faster settling time with a slight sacrifice in DC performance.

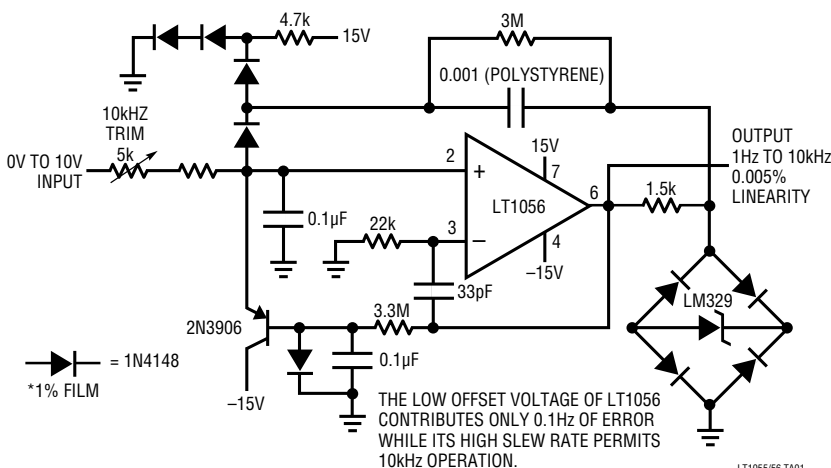
The voltage-to-frequency converter shown below is one of the many applications which utilize both the precision and high speed of the LT1055/LT1056.

For a JFET input op amp with 23V/μs guaranteed slew rate, refer to the LT1022 data sheet.

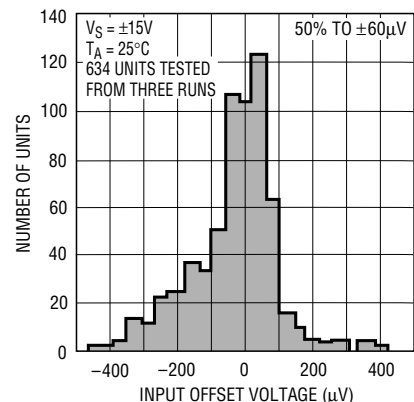
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## TYPICAL APPLICATION

0kHz to 10kHz Voltage-to-Frequency Converter



Distribution of Input Offset Voltage  
(H Package)

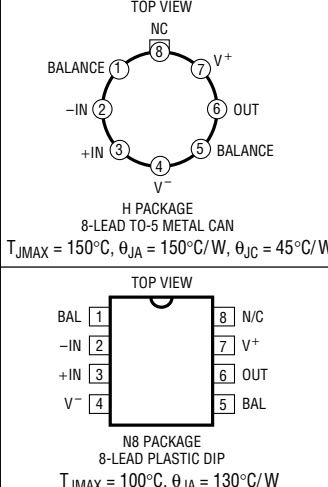


# LT1055/LT1056

## ABSOLUTE MAXIMUM RATINGS

|   |                                  |
|---|----------------------------------|
| Supply Voltage .....                        | $\pm 20V$                        |
| Differential Input Voltage .....            | $\pm 40V$                        |
| Input Voltage .....                         | $\pm 20V$                        |
| Output Short-Circuit Duration .....         | Indefinite                       |
| Operating Temperature Range                 |                                  |
| LT1055AM/LT1055M/LT1056AM/<br>LT1056M ..... | $-55^{\circ}C$ to $125^{\circ}C$ |
| LT1055AC/LT1055C/LT1056AC/<br>LT1056C ..... | $0^{\circ}C$ to $70^{\circ}C$    |
| Storage Temperature Range                   |                                  |
| All Devices .....                           | $-65^{\circ}C$ to $150^{\circ}C$ |
| Lead Temperature (Soldering, 10 sec) .....  | $300^{\circ}C$                   |

## PACKAGE/ORDER INFORMATION

|  | ORDER PART NUMBER      |           |
|--|------------------------|-----------|
|  | LT1055ACH              | LT1056ACH |
|  | LT1055CH               | LT1056CH  |
|  | LT1055AMH              | LT1056AMH |
|  | LT1055MH               | LT1056MH  |
|  | LT1055CN8<br>LT1056CN8 |           |

Consult factory for Industrial grade parts.

## ELECTRICAL CHARACTERISTICS $V_S = \pm 15V$ , $T_A = 25^{\circ}C$ , $V_{CM} = 0V$ unless otherwise noted.

| SYMBOL    | PARAMETER                                     | CONDITIONS   | LT1055AM/LT1056AM<br>LT1055AC/LT1056AC |            |          | LT1055M/LT1056M<br>LT1055CH/LT1056CH<br>LT1055CN8/LT1056CN8 |            |          | UNITS          |
|-----------|---|--|--|------------|----------|---|------------|----------|----------------|
|           |   |  | MIN                                    | TYP        | MAX      | MIN   | TYP        | MAX      |                |
| $V_{OS}$  | Input Offset Voltage (Note 1)                 | LT1055 H Package<br>LT1056 H Package<br>LT1055 N8 Package<br>LT1056 N8 Package | —                                      | 50         | 150      | —   | 70         | 400      | $\mu V$        |
| $I_{OS}$  | Input Offset Current                          | Fully Warmup   | —                                      | 2          | 10       | —   | 2          | 20       | pA             |
| $I_B$     | Input Bias Current                            | Fully Warmup<br>$V_{CM} = 10V$   | —                                      | $\pm 10$   | $\pm 50$ | —   | $\pm 10$   | $\pm 50$ | pA             |
|           | Input Resistance: Differential<br>Common Mode | $V_{CM} = -11V$ to $8V$<br>$V_{CM} = 8V$ to $11V$                              | —                                      | $10^{12}$  | —        | —   | $10^{12}$  | —        | $\Omega$       |
|           |   |  | —                                      | $10^{12}$  | —        | —   | $10^{12}$  | —        | $\Omega$       |
|           | Input Capacitance                             |  | —                                      | 4          | —        | —   | 4          | —        | pF             |
| $e_n$     | Input Noise Voltage                           | 0.1Hz to 10Hz LT1055<br>LT1056   | —                                      | 1.8        | —        | —   | 2.0        | —        | $\mu V_{P-P}$  |
|           | Input Noise Voltage Density                   | $f_0 = 10Hz$ (Note 2)<br>$f_0 = 1kHz$ (Note 3)                                 | —                                      | 28         | 50       | —   | 30         | 60       | $nV/\sqrt{Hz}$ |
| $I_n$     | Input Noise Current Density                   | $f_0 = 10Hz, 1kHz$ (Note 4)  | —                                      | 1.8        | 4        | —   | 1.8        | 4        | $fA/\sqrt{Hz}$ |
| $A_{VOL}$ | Large-Signal Voltage Gain                     | $V_0 = \pm 10V$ $R_L = 2k$<br>$R_L = 1k$                                       | 150                                    | 400        | —        | 120   | 400        | —        | V/mV           |
|           | Input Voltage Range                           |  | $\pm 11$                               | $\pm 12$   | —        | $\pm 11$  | $\pm 12$   | —        | V              |
| CMRR      | Common-Mode Rejection Ratio                   | $V_{CM} = \pm 11V$   | 86                                     | 100        | —        | 83  | 98         | —        | dB             |
| PSRR      | Power Supply Rejection Ratio                  | $V_S = \pm 10V$ to $\pm 18V$   | 90                                     | 106        | —        | 88  | 104        | —        | dB             |
| $V_{OUT}$ | Output Voltage Swing                          | $R_L = 2k$   | $\pm 12$                               | $\pm 13.2$ | —        | $\pm 12$  | $\pm 13.2$ | —        | V              |
| SR        | Slew Rate                                     | LT1055   | 10                                     | 13         | —        | 7.5   | 12         | —        | V/ $\mu s$     |
|           |   | LT1056   | 12                                     | 16         | —        | 9.0   | 14         | —        | V/ $\mu s$     |
| GBW       | Gain-Bandwidth Product                        | $f = 1MHz$ LT1055  | —                                      | 5.0        | —        | —   | 4.5        | —        | MHz            |
|           |   | LT1056   | —                                      | 6.5        | —        | —   | 5.5        | —        | MHz            |
| $I_S$     | Supply Current                                | LT1055   | —                                      | 2.8        | 4.0      | —   | 2.8        | 4.0      | mA             |
|           |   | LT1056   | —                                      | 5.0        | 6.5      | —   | 5.0        | 7.0      | mA             |
|           | Offset Voltage Adjustment Range               | $R_{POT} = 100k$   | —                                      | $\pm 5$    | —        | —   | $\pm 5$    | —        | mV             |

# ELECTRICAL CHARACTERISTICS

$V_S = \pm 15V$ ,  $V_{CM} = 0V$ ,  $0^\circ C \leq T_A \leq 70^\circ C$  unless otherwise noted.

| SYMBOL    | PARAMETER   | CONDITIONS                   |   | LT1055AC<br>LT1056AC |            |           | LT1055CH/LT1056CH<br>LT1055CN8/LT1056CN8 |            |           | UNITS            |
|-----------|---|------------------------------|---|----------------------|------------|-----------|--|------------|-----------|------------------|
|           |   |                              |   | MIN                  | TYP        | MAX       | MIN                                      | TYP        | MAX       |                  |
| $V_{OS}$  | Input Offset Voltage (Note1)                            | LT1055 H Package             | ● | —                    | 100        | 330       | —  | 140        | 750       | $\mu V$          |
|           |   | LT1056 H Package             | ● | —                    | 100        | 360       | —  | 140        | 800       | $\mu V$          |
|           |   | LT1055 N8 Package            | ● | —                    | —          | —         | —  | 250        | 1250      | $\mu V$          |
|           |   | LT1056 N8 Package            | ● | —                    | —          | —         | —  | 280        | 1350      | $\mu V$          |
|           | Average Temperature Coefficient of Input Offset Voltage | H Package (Note 5)           | ● | —                    | 1.2        | 4.0       | —  | 1.6        | 8.0       | $\mu V/^\circ C$ |
|           |   | N8 Package (Note 5)          | ● | —                    | —          | —         | —  | 3.0        | 12.0      | $\mu V/^\circ C$ |
| $I_{OS}$  | Input Offset Current                                    | Warmed Up LT1055             | ● | —                    | 10         | 50        | —  | 16         | 80        | pA               |
|           |   | $T_A = 70^\circ C$ LT1056    | ● | —                    | 14         | 70        | —  | 18         | 100       | pA               |
| $I_B$     | Input Bias Current                                      | Warmed Up LT1055             | ● | —                    | $\pm 30$   | $\pm 150$ | —  | $\pm 40$   | $\pm 200$ | pA               |
|           |   | $T_A = 70^\circ C$ LT1056    | ● | —                    | $\pm 40$   | $\pm 80$  | —  | $\pm 50$   | $\pm 240$ | pA               |
| $A_{VOL}$ | Large-Signal Voltage Gain                               | $V_O = \pm 10V$ , $R_L = 2k$ | ● | 80                   | 250        | —         | 60                                       | 250        | —         | V/mV             |
| CMRR      | Common-Mode Rejection Ratio                             | $V_{CM} = \pm 10.5V$         | ● | 85                   | 100        | —         | 82                                       | 98         | —         | dB               |
| PSRR      | Power Supply Rejection Ratio                            | $V_S = \pm 10V$ to $\pm 18V$ | ● | 89                   | 105        | —         | 87                                       | 103        | —         | dB               |
| $V_{OUT}$ | Output Voltage Swing                                    | $R_L = 2k$                   | ● | $\pm 12$             | $\pm 13.1$ | —         | $\pm 12$                                 | $\pm 13.1$ | —         | V                |

$V_S = \pm 15V$ ,  $V_{CM} = 0V$ ,  $-55^\circ C \leq T_A \leq 125^\circ C$  unless otherwise noted.

| SYMBOL    | PARAMETER   | CONDITIONS                   |   | LT1055AM<br>LT1056AM |            |           | LT1055M<br>LT1056M |            |           | UNITS            |
|-----------|---|------------------------------|---|----------------------|------------|-----------|--------------------|------------|-----------|------------------|
|           |   |                              |   | MIN                  | TYP        | MAX       | MIN                | TYP        | MAX       |                  |
| $V_{OS}$  | Input Offset Voltage (Note1)                            | LT1055                       | ● | —                    | 180        | 500       | —                  | 250        | 1200      | $\mu V$          |
|           |   | LT1056                       | ● | —                    | 180        | 550       | —                  | 250        | 1250      | $\mu V$          |
|           | Average Temperature Coefficient of Input Offset Voltage | (Note 5)                     | ● | —                    | 1.3        | 4.0       | —                  | 1.8        | 8.0       | $\mu V/^\circ C$ |
| $I_{OS}$  | Input Offset Current                                    | Warmed Up LT1055             | ● | —                    | 0.20       | 1.2       | —                  | 0.25       | 1.8       | nA               |
|           |   | $T_A = 125^\circ C$ LT1056   | ● | —                    | 0.25       | 1.5       | —                  | 0.30       | 2.4       | nA               |
| $I_B$     | Input Bias Current                                      | Warmed Up LT1055             | ● | —                    | $\pm 0.4$  | $\pm 2.5$ | —                  | $\pm 0.5$  | $\pm 4.0$ | nA               |
|           |   | $T_A = 125^\circ C$ LT1056   | ● | —                    | $\pm 0.5$  | $\pm 3.0$ | —                  | $\pm 0.6$  | $\pm 5.0$ | nA               |
| $A_{VOL}$ | Large-Signal Voltage Gain                               | $V_O = \pm 10V$ , $R_L = 2k$ | ● | 40                   | 120        | —         | 35                 | 120        | —         | V/mV             |
| CMRR      | Common-Mode Rejection Ratio                             | $V_{CM} = \pm 10.5V$         | ● | 85                   | 100        | —         | 82                 | 98         | —         | dB               |
| PSRR      | Power Supply Rejection Ratio                            | $V_S = \pm 10V$ to $\pm 17V$ | ● | 88                   | 104        | —         | 86                 | 102        | —         | dB               |
| $V_{OUT}$ | Output Voltage Swing                                    | $R_L = 2k$                   | ● | $\pm 12$             | $\pm 12.9$ | —         | $\pm 12$           | $\pm 12.9$ | —         | V                |

The ● denotes specifications which apply over the full operating temperature range.

For MIL-STD components, please refer to LTC883 data sheet for test listing and parameters.

**Note 1:** Offset voltage is measured under two different conditions: (a) approximately 0.5 seconds after application of power; (b) at  $T_A = 25^\circ C$  only, with the chip heated to approximately  $38^\circ C$  for the LT1055 and to  $45^\circ C$  for the LT1056, to account for chip temperature rise when the device is fully warmed up.

**Note 2:** 10Hz noise voltage density is sample tested on every lot of A grades. Devices 100% tested at 10Hz are available on request.

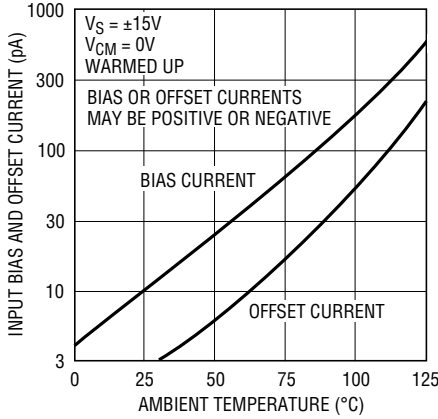
**Note 3:** This parameter is tested on a sample basis only.

**Note 4:** Current noise is calculated from the formula:  $i_n = (2qI_B)^{1/2}$ , where  $q = 1.6 \times 10^{-19}$  coulomb. The noise of source resistors up to  $1G\Omega$  swamps the contribution of current noise.

**Note 5:** Offset voltage drift with temperature is practically unchanged when the offset voltage is trimmed to zero with a 100k potentiometer between the balance terminals and the wiper tied to  $V^+$ . Devices tested to tighter drift specifications are available on request.

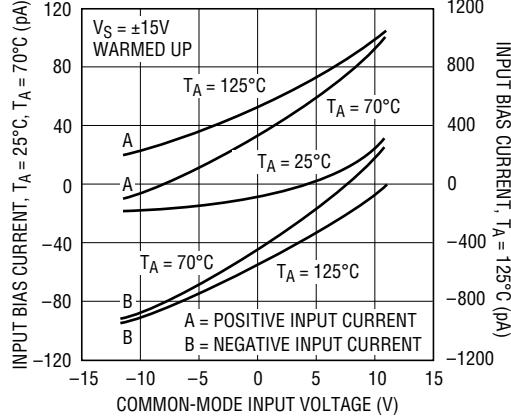
# TYPICAL PERFORMANCE CHARACTERISTICS

**Input Bias and Offset Currents vs Temperature**



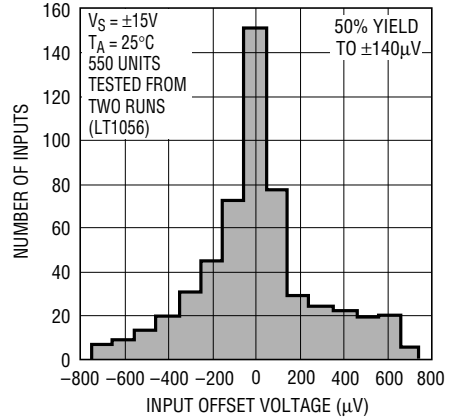
LT1055/56 G01

**Input Bias Current Over the Common-Mode Range**



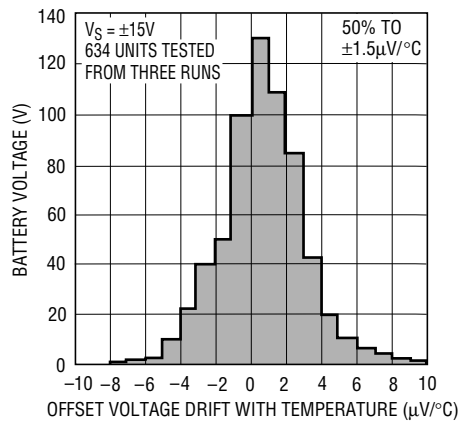
LT1055/56 G02

**Distribution of Input Offset Voltage (N8 Package)**



LT1055/56 G03

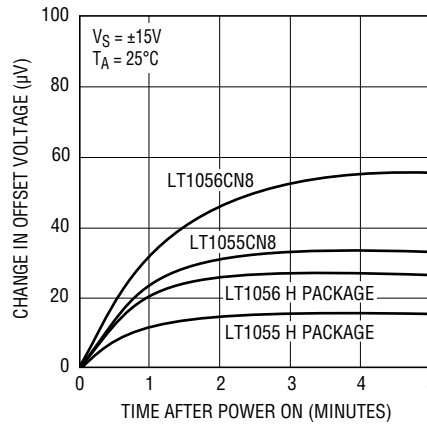
**Distribution of Offset Voltage Drift with Temperature (H Package)\***



\*DISTRIBUTION IN THE PLASTIC (N8) PACKAGE IS SIGNIFICANTLY WIDER.

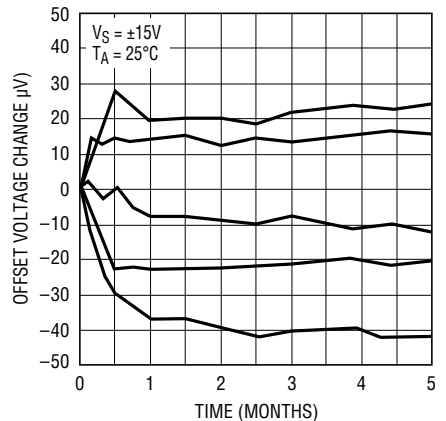
LT1055/56 G04

**Warm-Up Drift**



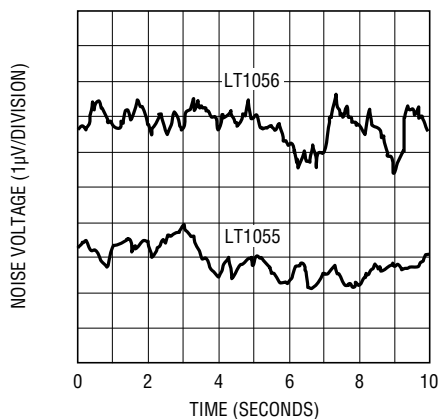
LT1055/56 G05

**Long Term Drift of Representative Units**



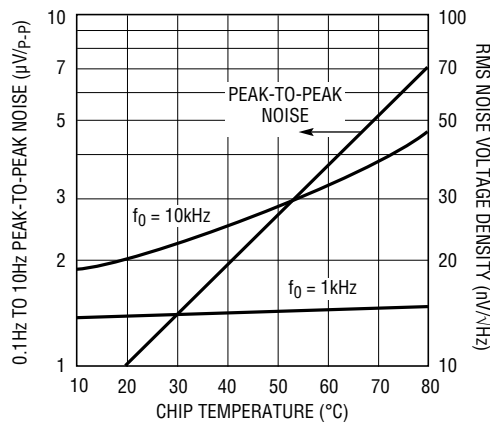
LT1055/56 G06

**0.1Hz to 10Hz Noise**



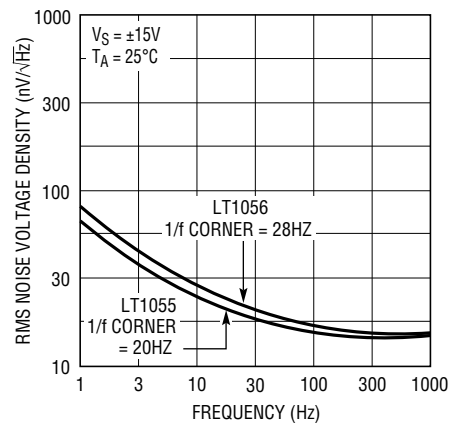
LT1055/56 G07

**Noise vs Chip Temperature**



LT1055/56 G08

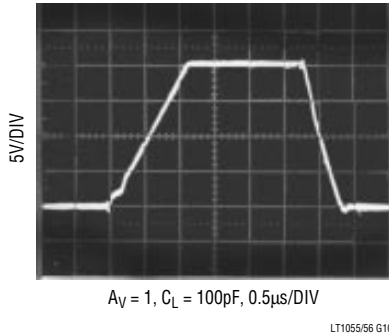
**Voltage Noise vs Frequency**



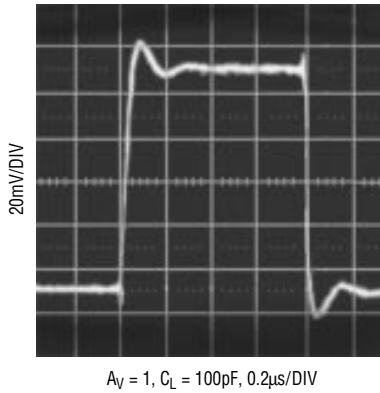
LT1055/56 G09

# TYPICAL PERFORMANCE CHARACTERISTICS

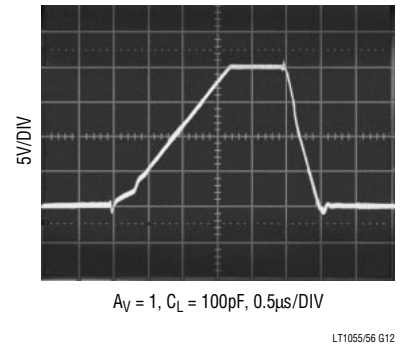
LT1056 Large-Signal Response



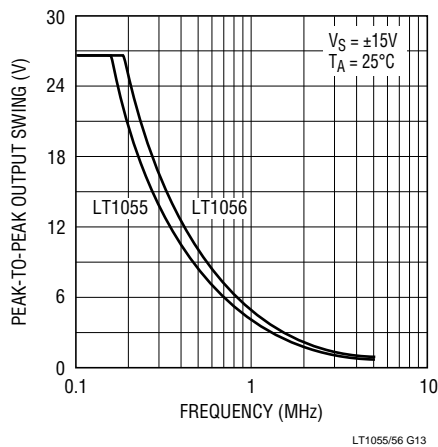
Small-Signal Response



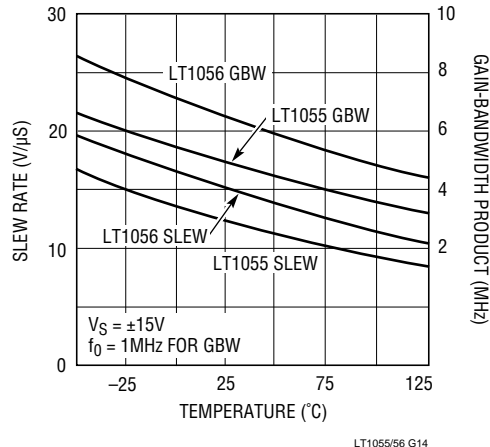
LT1055 Large-Signal Response



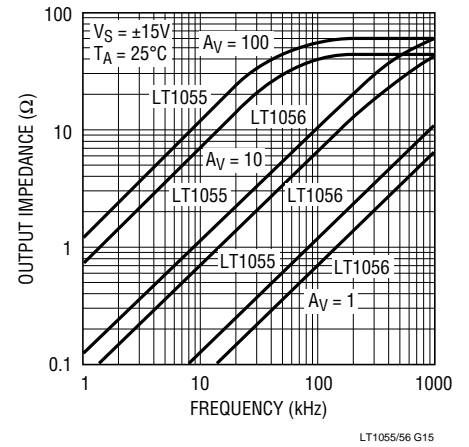
Undistorted Output Swing vs Frequency



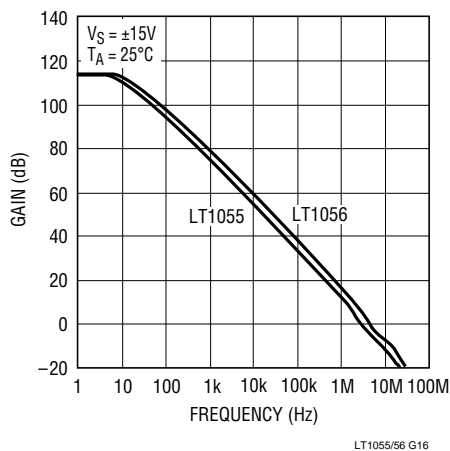
Slew Rate, Gain-Bandwidth vs Temperature



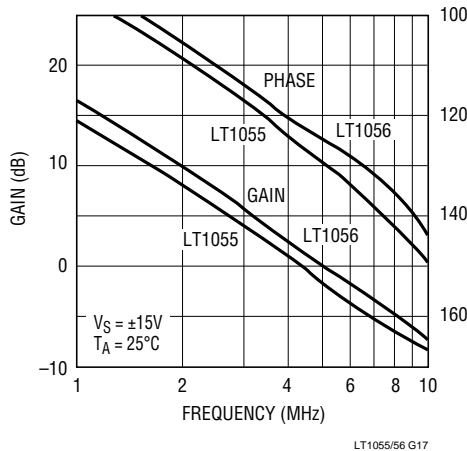
Output Impedance vs Frequency



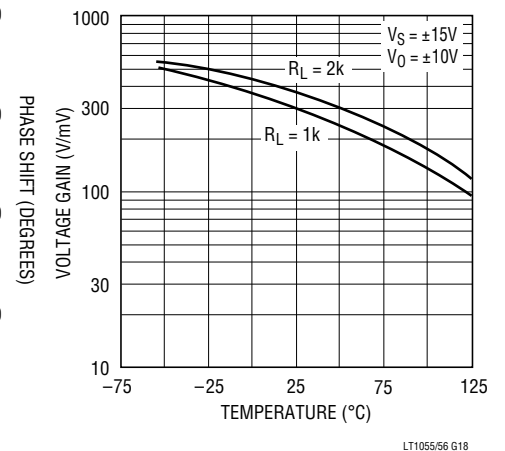
Gain vs Frequency



Gain, Phase Shift vs Frequency

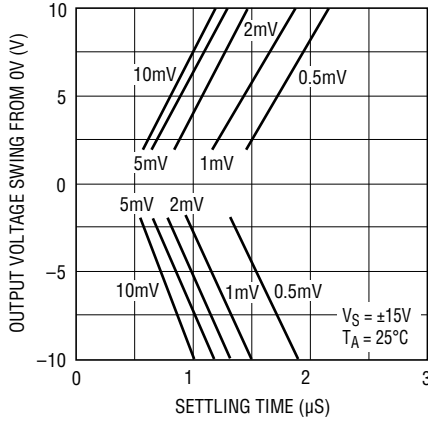


Voltage Gain vs Temperature



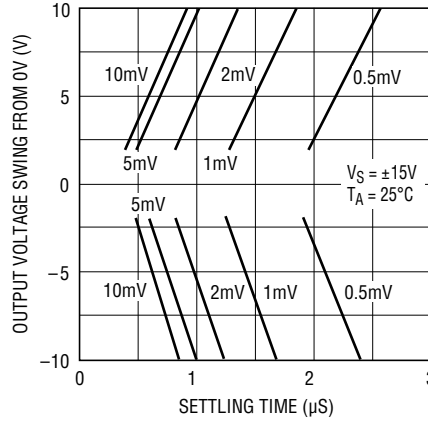
## TYPICAL PERFORMANCE CHARACTERISTICS

**LT1055 Settling Time**



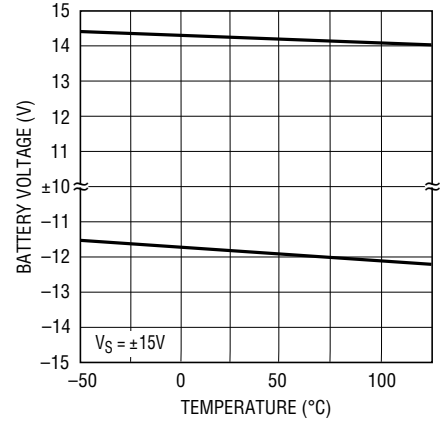
LT1055/56 G19

**LT1056 Settling Time**



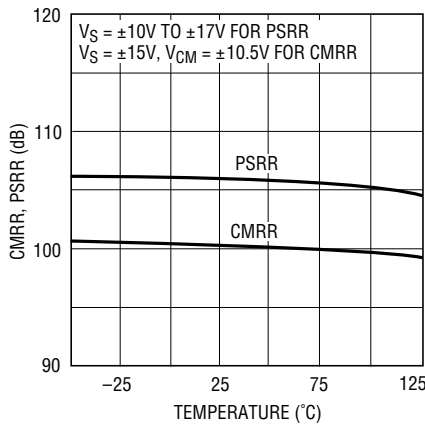
LT1055/56 G20

**Common-Mode Range vs Temperature**



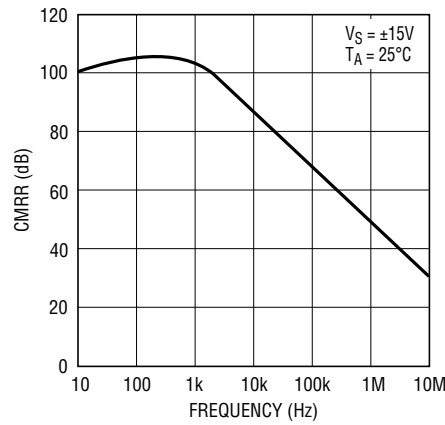
LT1055/56 G21

**Common-Mode and Power Supply Rejections vs Temperature**



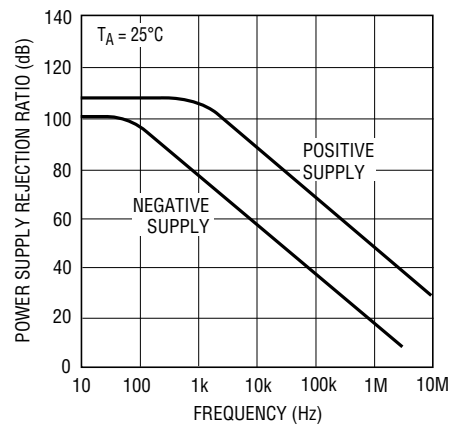
LT1055/56 G22

**Common-Mode Rejection Ratio vs Frequency**



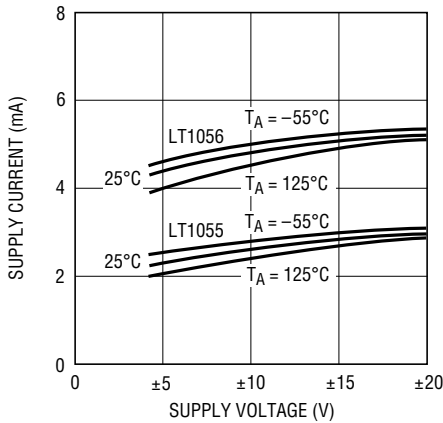
LT1055/56 G23

**Power Supply Rejection Ratio vs Frequency**



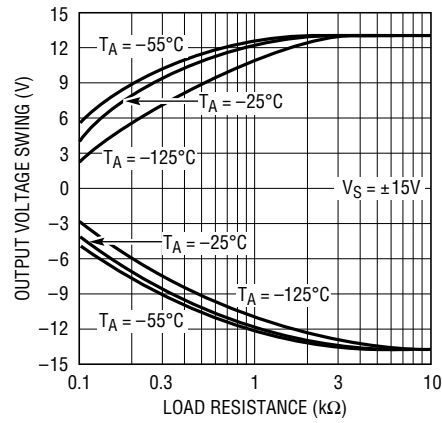
LT1055/56 G24

**Supply Current vs Supply Voltage**



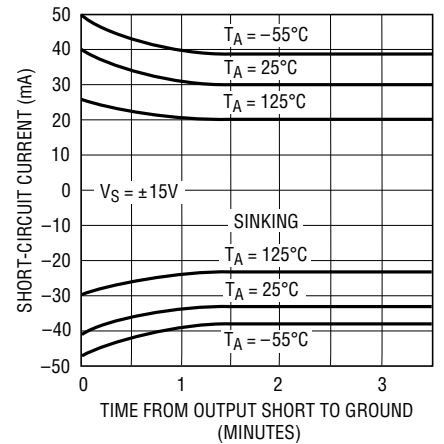
LT1055/56 G25

**Output Swing vs Load Resistance**



LT1055/56 G26

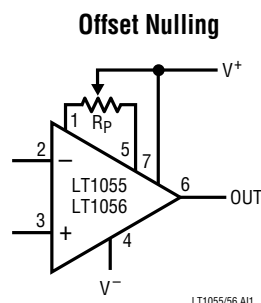
**Short-Circuit Current vs Time**



LT1055/56 G27

## APPLICATIONS INFORMATION

The LT1055/LT1056 may be inserted directly into LF155A/LT355A, LF156A/LT356A, OP-15 and OP-16 sockets. Offset nulling will be compatible with these devices with the wiper of the potentiometer tied to the positive supply.



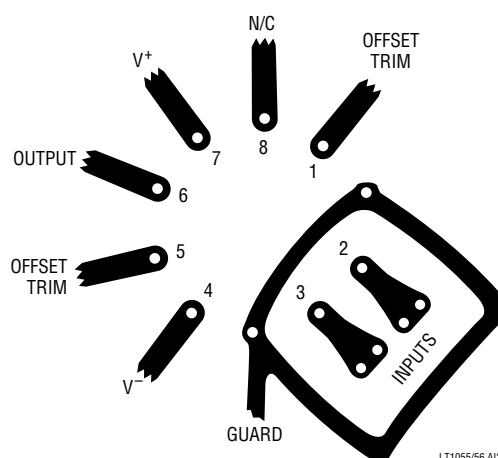
No appreciable change in offset voltage drift with temperature will occur when the device is nulled with a potentiometer,  $R_p$ , ranging from 10k to 200k.

The LT1055/LT1056 can also be used in LF351, LF411, AD547, AD611, OPA-111, and TL081 sockets, provided that the nulling circuitry is removed. Because of the LT1055/LT1056's low offset voltage, nulling will not be necessary in most applications.

### Achieving Picoampere/Microvolt Performance

In order to realize the picoampere-microvolt level accuracy of the LT1055/LT1056 proper care must be exercised. For example, leakage currents in circuitry external to the op amp can significantly degrade performance. High quality insulation should be used (e.g. Teflon™, Kel-F); cleaning of all insulating surfaces to remove fluxes and other residues will probably be required. Surface coating may be necessary to provide a moisture barrier in high humidity environments.

Board leakage can be minimized by encircling the input circuitry with a guard ring operated at a potential close to that of the inputs: in inverting configurations the guard ring should be tied to ground, in noninverting connections to the inverting input at pin 2. Guarding both sides of the printed circuit board is required. Bulk leakage reduction depends on the guard ring width.



The LT1055/LT1056 has the lowest offset voltage of any JFET input op amp available today. However, the offset voltage and its drift with time and temperature are still not as good as on the best bipolar amplifiers because the transconductance of FETs is considerably lower than that of bipolar transistors. Conversely, this lower transconductance is the main cause of the significantly faster speed performance of FET input op amps.

Offset voltage also changes somewhat with temperature cycling. The AM grades show a typical 20μV hysteresis (30μV on the M grades) when cycled over the -55°C to 125°C temperature range. Temperature cycling from 0°C to 70°C has a negligible (less than 10μV) hysteresis effect.

The offset voltage and drift performance are also affected by packaging. In the plastic N8 package the molding compound is in direct contact with the chip, exerting pressure on the surface. While NPN input transistors are largely unaffected by this pressure, JFET device matching and drift are degraded. Consequently, for best DC performance, as shown in the typical performance distribution plots, the TO-5 H package is recommended.

### Noise Performance

The current noise of the LT1055/LT1056 is practically immeasurable at  $1.8\text{fA}/\sqrt{\text{Hz}}$ . At 25°C it is negligible up to 1G of source resistance,  $R_S$  (compound to the noise of  $R_S$ ). Even at 125°C it is negligible to 100M of  $R_S$ .

Teflon is a trademark of Dupont.

## APPLICATIONS INFORMATION

The voltage noise spectrum is characterized by a low  $1/f$  corner in the 20Hz to 30Hz range, significantly lower than on other competitive JFET input op amps. Of particular interest is the fact that with any JFET IC amplifier, the frequency location of the  $1/f$  corner is proportional to the square root of the internal gate leakage currents and, therefore, noise doubles every 20°C. Furthermore, as illustrated in the noise versus chip temperature curves, the 0.1Hz to 10Hz peak-to-peak noise is a strong function of temperature, while wideband noise ( $f_0 = 1\text{kHz}$ ) is practically unaffected by temperature.

Consequently, for optimum low frequency noise, chip temperature should be minimized. For example, operating an LT1056 at  $\pm 5V$  supplies or with a  $20^{\circ}C/W$  case-to-ambient heat sink reduces 0.1Hz to 10Hz noise from typically  $2.5\mu V_{P-P}$  ( $\pm 15V$ , free-air) to  $1.5\mu V_{P-P}$ . Similarly, the noise of an LT1055 will be  $1.8\mu V_{P-P}$  typically because of its lower power dissipation and chip temperature.

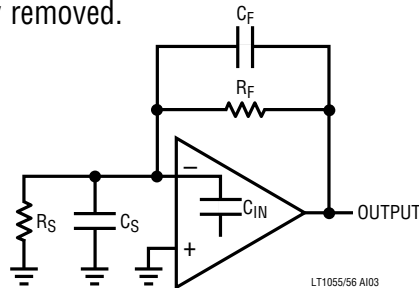
## High Speed Operation

Settling time is measured in the test circuit shown. This test configuration has two features which eliminate problems common to settling time measurements: (1) probe

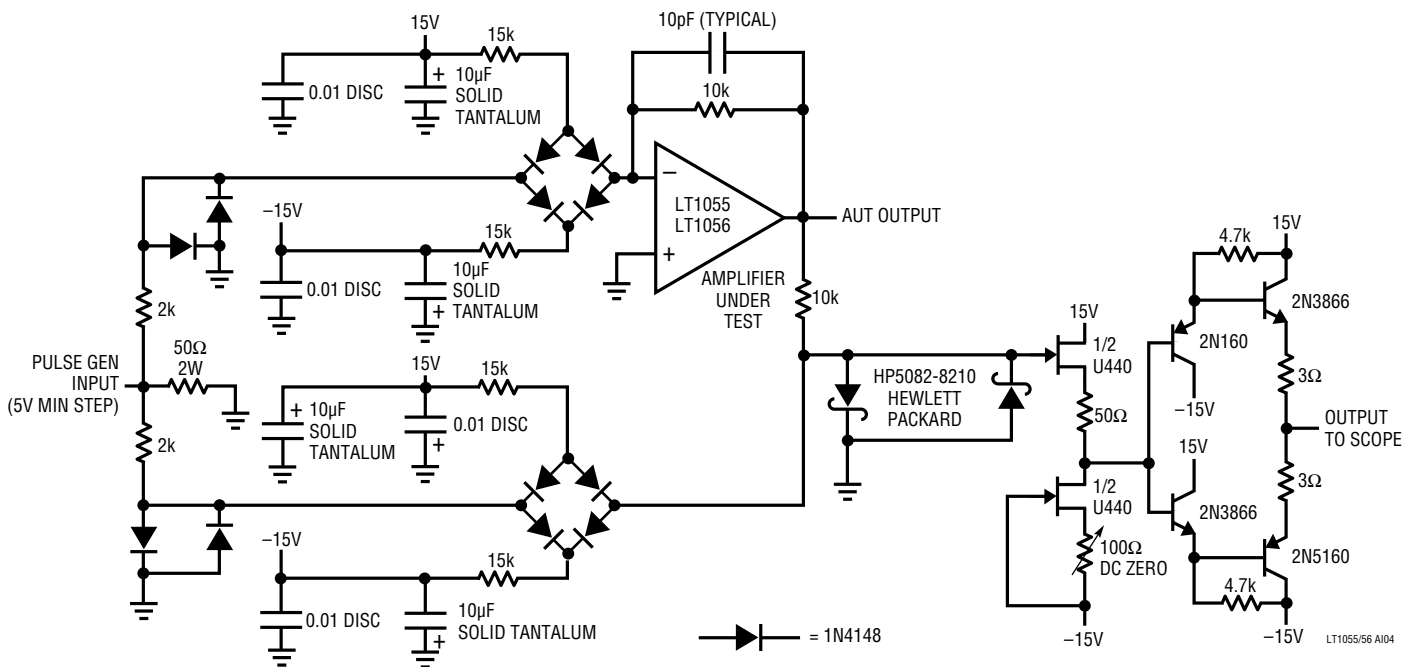
capacitance is isolated from the “false summing” node. and (2) it does not require a “flat top” input pulse since the input pulse is merely used to steer current through the diode bridges. For more details, please see Application Note 10.

As with most high speed amplifiers, care should be taken with supply decoupling, lead dress and component placement.

When the feedback around the op amp is resistive ( $R_F$ ), a pole will be created with  $R_F$ , the source resistance and capacitance ( $R_S$ ,  $C_S$ ), and the amplifier input capacitance ( $C_{IN} \approx 4\text{pF}$ ). In low closed-loop gain configurations and with  $R_S$  and  $R_F$  in the kilohm range, this pole can create excess phase shift and even oscillation. A small capacitor ( $C_F$ ) in parallel with  $R_F$  eliminates this problem. With  $R_S(C_S + C_{IN}) = R_FC_F$ , the effect of the feedback pole is completely removed.



## Settling Time Test Circuit



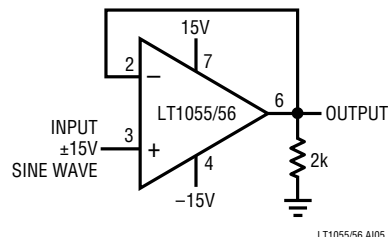


## APPLICATIONS INFORMATION

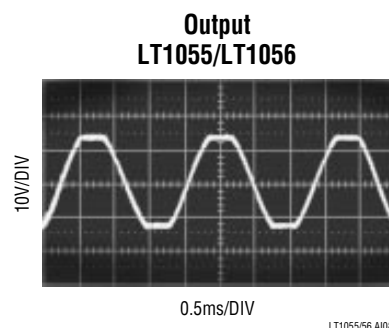
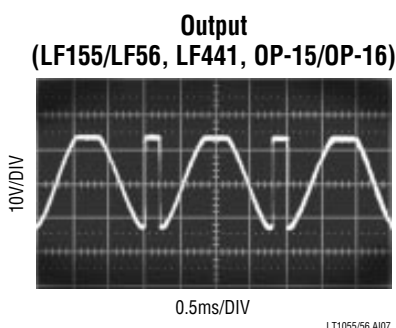
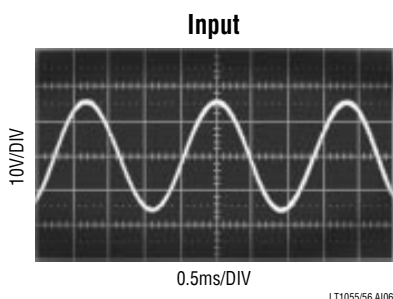
### Phase Reversal Protection

Most industry standard JFET input op amps (e.g., LF155/LF156, LF351, LF411, OP15/16) exhibit phase reversal at the output when the negative common-mode limit at the input is exceeded (i.e., from  $-12\text{V}$  to  $-15\text{V}$  with  $\pm 15\text{V}$  supplies). This can cause lock-up in servo systems. As shown below, the LT1055/LT1056 does not have this problem due to unique phase reversal protection circuitry (Q1 on simplified schematic).

### Voltage Follower with Input Exceeding the Negative Common-Mode Range

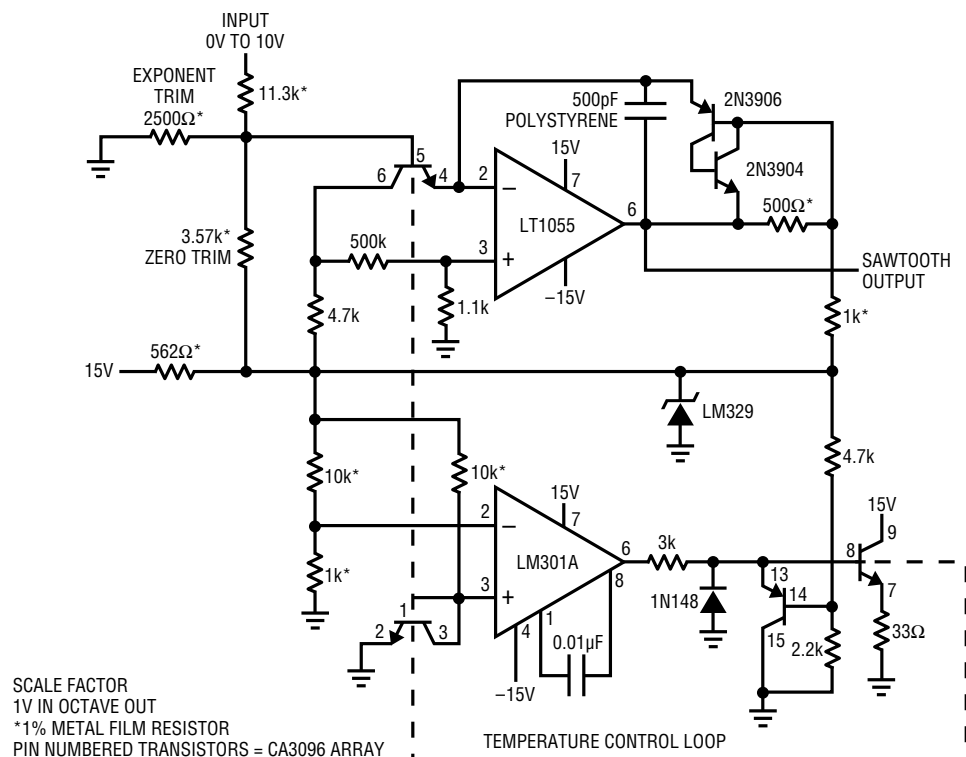


LT1055/56 A105



## TYPICAL APPLICATIONS <sup>†</sup>

### Exponential Voltage-to-Frequency Converter for Music Synthesizers

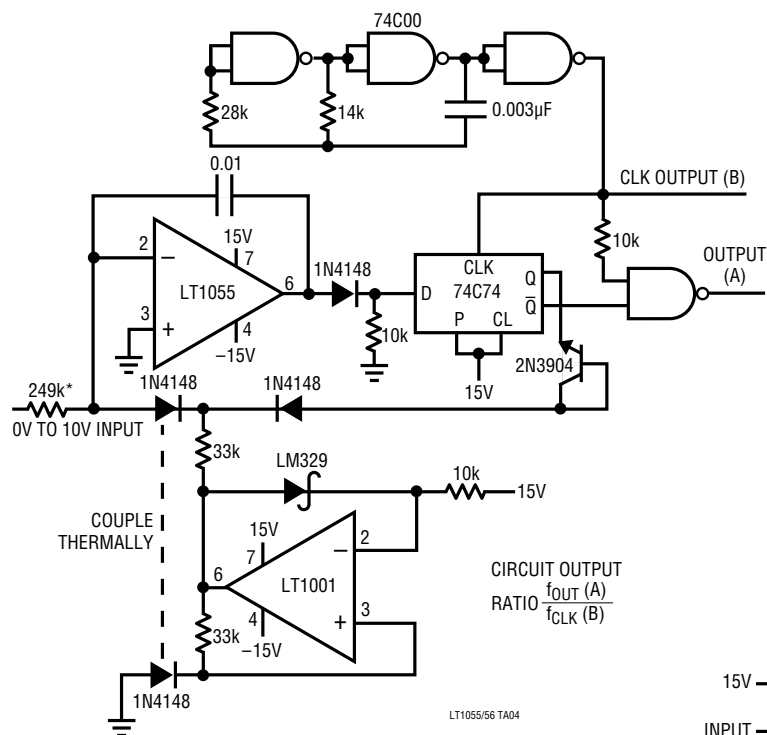


LT1055/56 TA03

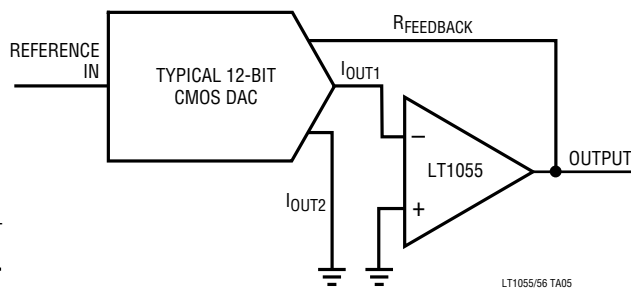
<sup>†</sup>For ten additional applications utilizing the LT1055 and LT1056, please see the LTC1043 data sheet and Application Note 3.

## TYPICAL APPLICATIONS

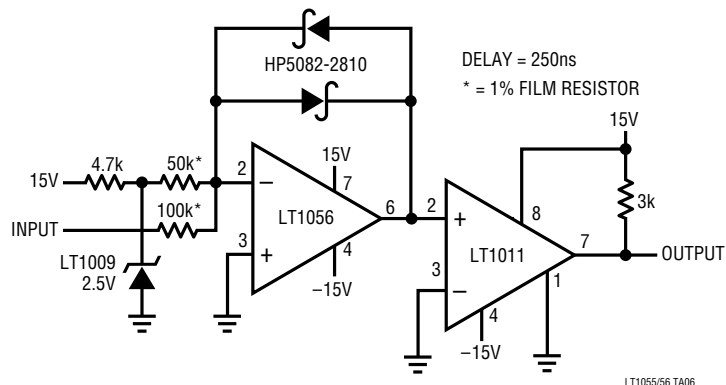
### 12-Bit Charge Balance A/D Converter



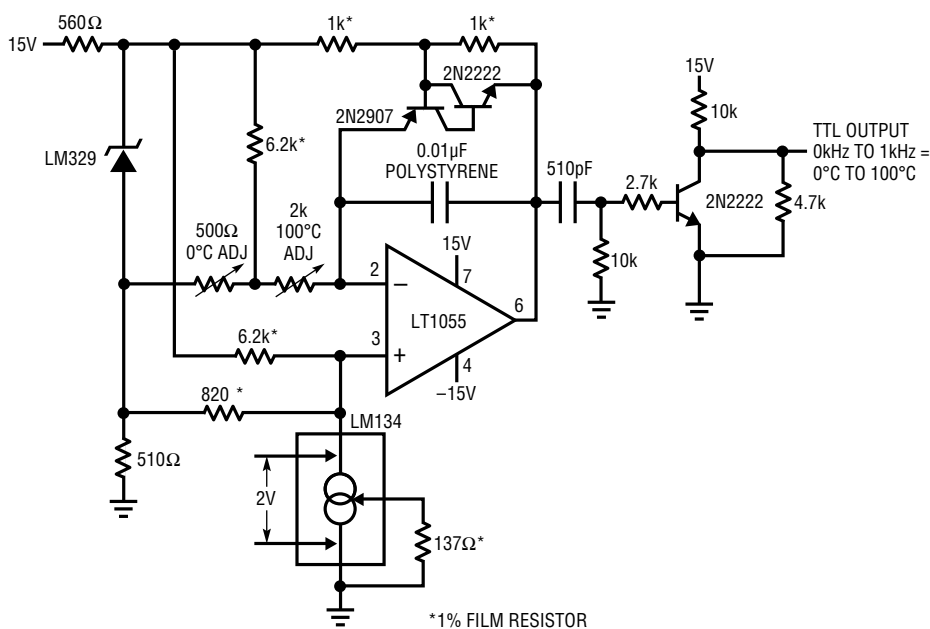
### Fast "No Trims" 12-Bit Multiplying CMOS DAC Amplifier



### Fast, 16-Bit Current Comparator



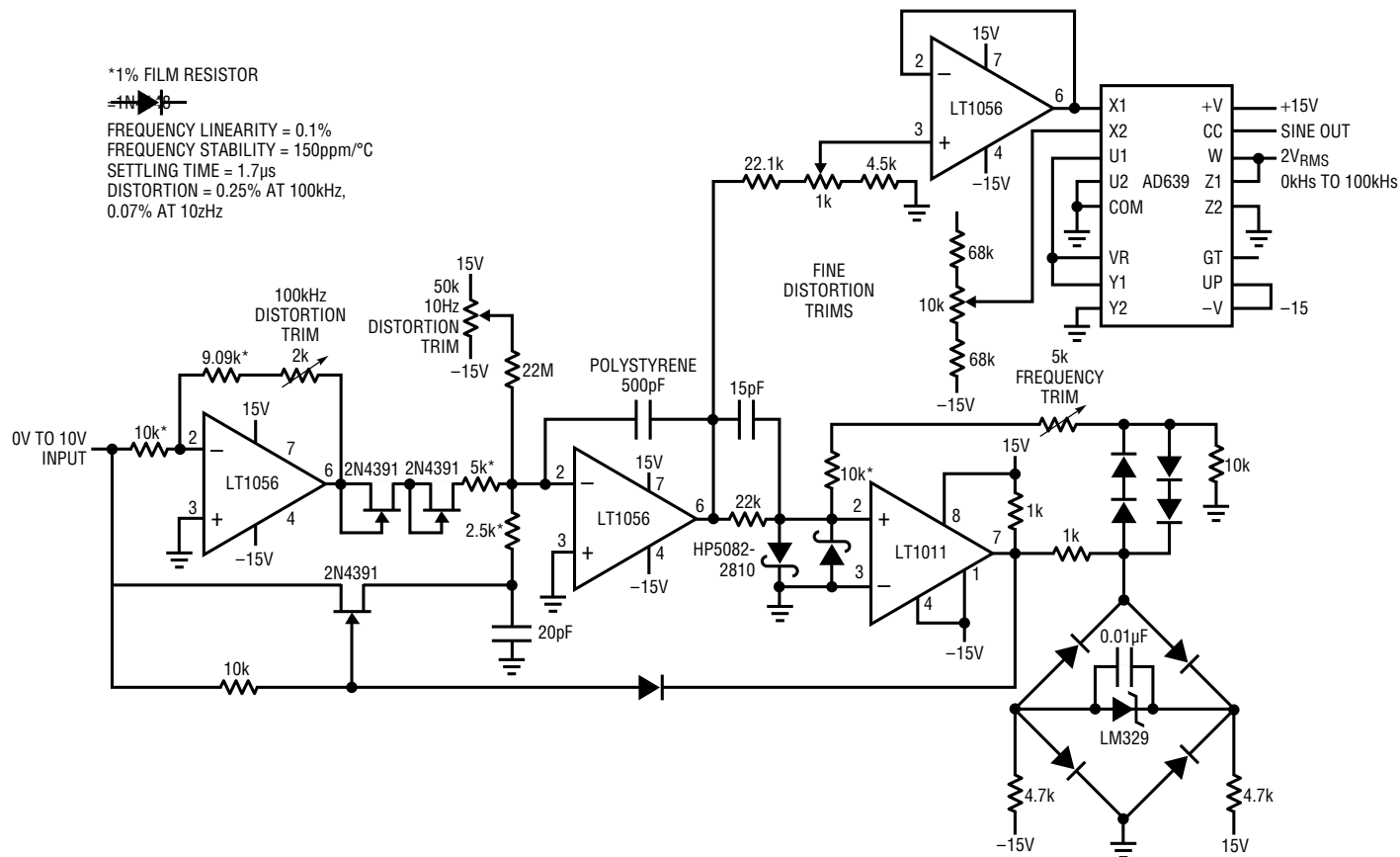
### Temperature-to-Frequency Converter



\*1% FILM RESISTOR

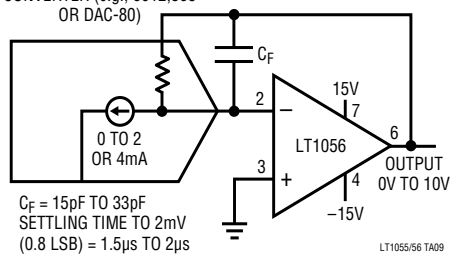
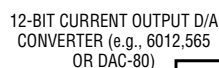


FREQUENCY LINEARITY = 0.1%  
FREQUENCY STABILITY = 150ppm/°C  
SETTLING TIME = 1.7μs  
DISTORTION = 0.25% AT 100kHz,  
0.07% AT 10kHz

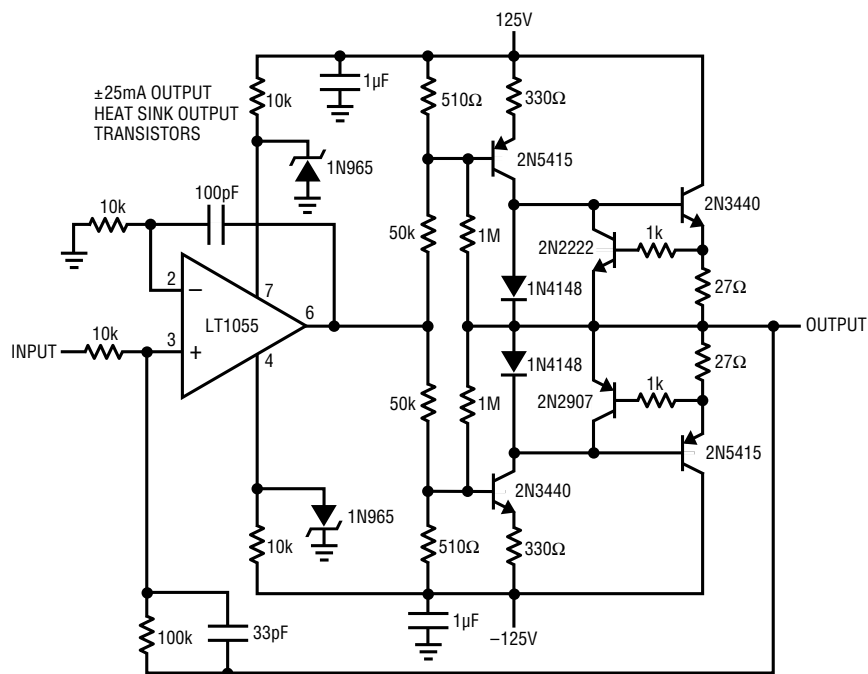


LT1055/56 TA08

## ±120V Output Precision Op Amp

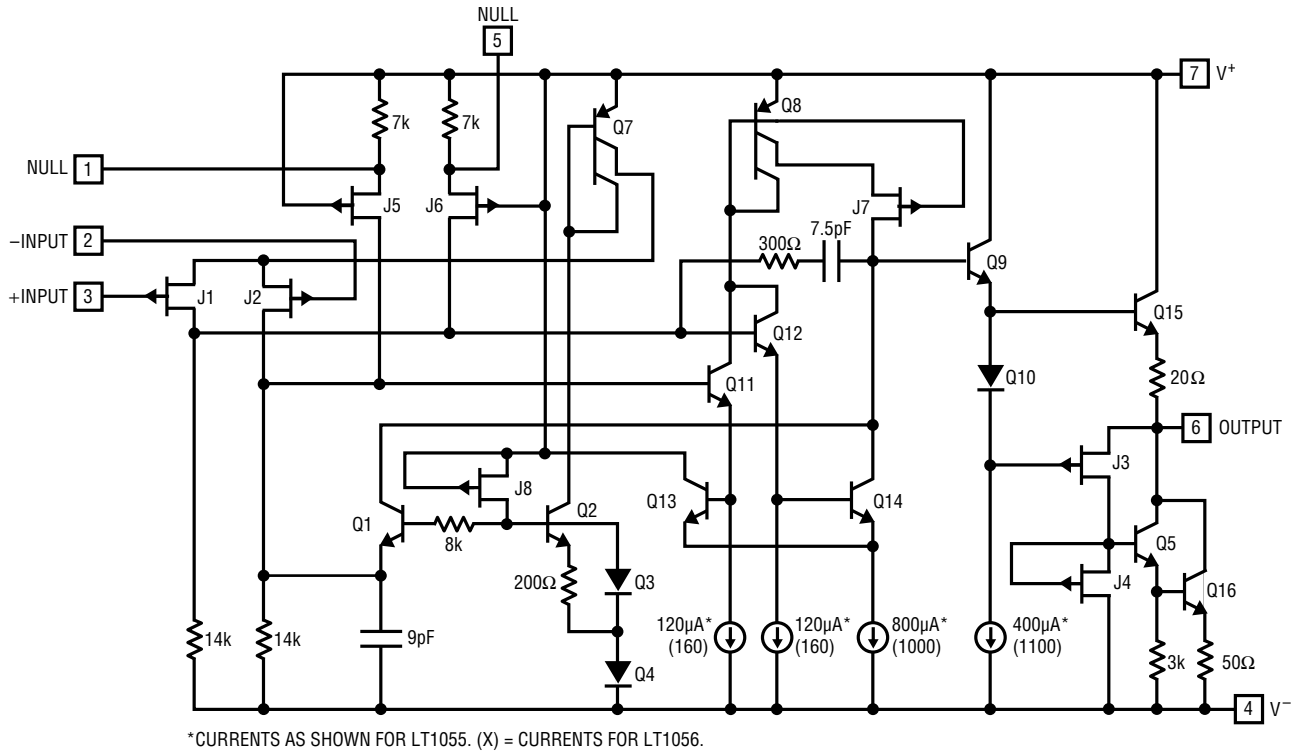


LT1055/56 TA09



LT1055/56 TA10

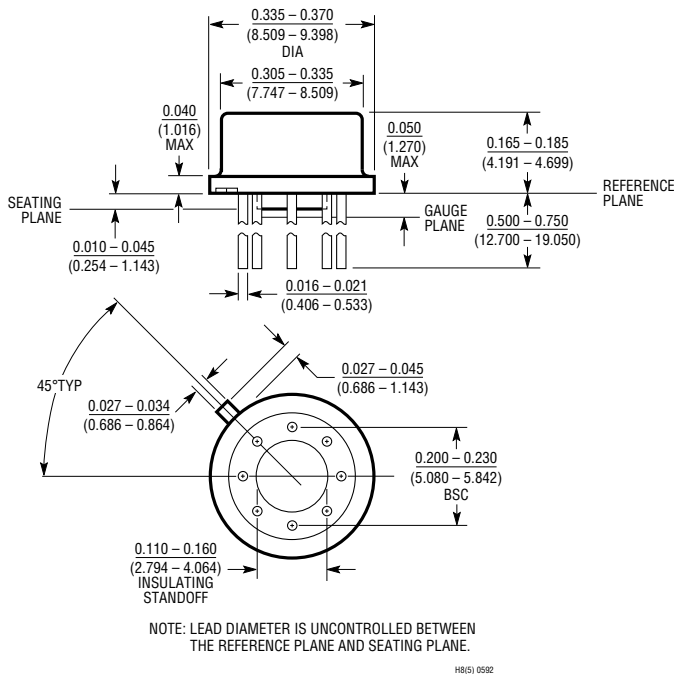
# SIMPLIFIED SCHEMATIC



## PACKAGE DESCRIPTION

Dimension in inches (millimeters) unless otherwise noted.

### H Package Metal Can



### N8 Package 8-Lead Plastic

